Appl. No. : 10/560,155 Filed : December 9, 2005

AMENDMENTS TO THE CLAIMS

 (Currently Amended) A developer composition for resists, comprising an organic quaternary ammonium base as a main component,

said developer composition further comprising an anionic surfactant represented by the following general formula (I):

$$\begin{array}{c}
R_1 \\
R_2
\end{array}$$

$$\begin{array}{c}
-0 \\
R_5
\end{array}$$

$$\begin{array}{c}
R_3 \\
R_4
\end{array}$$

$$\begin{array}{c}
\cdot \cdot \cdot \cdot (1)
\end{array}$$

wherein at least one of R_1 and R_2 represents an alkyl or alkoxy group having 5 to 18 carbon atoms and the other one represents a hydrogen atom, or an alkyl or alkoxy group having 5 to 18 carbon atoms, and at least one of R_3 , R_4 and R_5 represents an ammonium sulfonate group or a sulfonic acid-substituted ammonium group and the others represent a hydrogen atom, an ammonium sulfonate group or a sulfonic acid-substituted ammonium group;

SO42- in an amount from 10 to 10,000 ppm; and

- a lower alcohol in an amount from 0.05 to 2.5% by mass; and
- a halogen ion in an amount of 1,000 ppm or less.
- 2. (Canceled)
- 3. (Canceled)
- 4. (Previously presented) A method for formation of a resist pattern, comprising applying a resist composition on a substrate to form a resist layer, prebaking the resist layer, selectively exposing the prebaked resist layer to light, and alkali-developing the exposed resist layer with the developer composition for resists according to claim 1 to form a resist pattern.
- (New) The developer composition for resists according to claim 1, wherein said lower alcohol has 1 to 5 carbon atoms.
- (New) The developer composition for resists according to claim 5, wherein the lower alcohol is ethanol or methanol.